

## 1. General Description

The IT245 is a high-speed Si-gate CMOS device. IT245 is an octal transceiver featuring non-inverting 3-state bus compatible outputs in both send and receive directions. The IT245 features an output enable input ( $\overline{OE}$ ) for easy cascading and a send/receive input (DIR) for direction control.  $\overline{OE}$  controls the outputs so that the buses are effectively isolated.

The IT245 has true (non-inverting) outputs.

## 2. Features

- Octal bidirectional bus interface
- Non-inverting 3-state outputs
- Multiple package options
- Complies with JEDEC standard no. 7A
- ESD protection:
  - ◆ HBM EIA/JESD22-A114-B exceeds 2000V
  - ◆ MM EIA/JESD22-A115-A exceeds 200V
- Specified from -40°C to +85°C and from -40°C to +125°C

## 3. Quick reference data

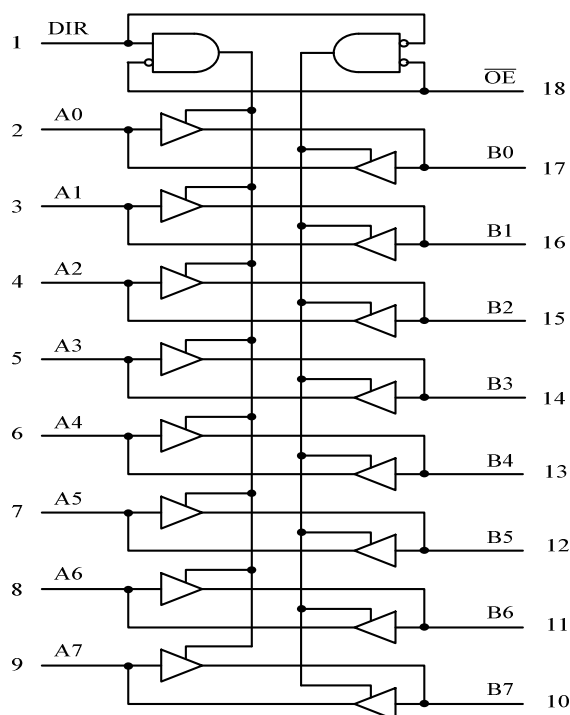
Table 1: Quick reference data

GND=0V;  $T_{amb}=25^{\circ}\text{C}$ ;  $t_r = t_f = 6\text{ns}$

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$t_{PHL}, t_{PLH}$	propagation delay An to Bn or Bn to An	$C_L=15\text{pF}; V_{CC}=5\text{V}$	-	5	-	ns
$C_I$	input capacitance		-	3.5	-	pF
$C_{I/O}$	input/output capacitance		-	10	-	pF
$C_{PD}$	power dissipation capacitance per transceiver	$V_I=\text{GND to } V_{CC}^*$	-	12	-	pF

\*  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ )

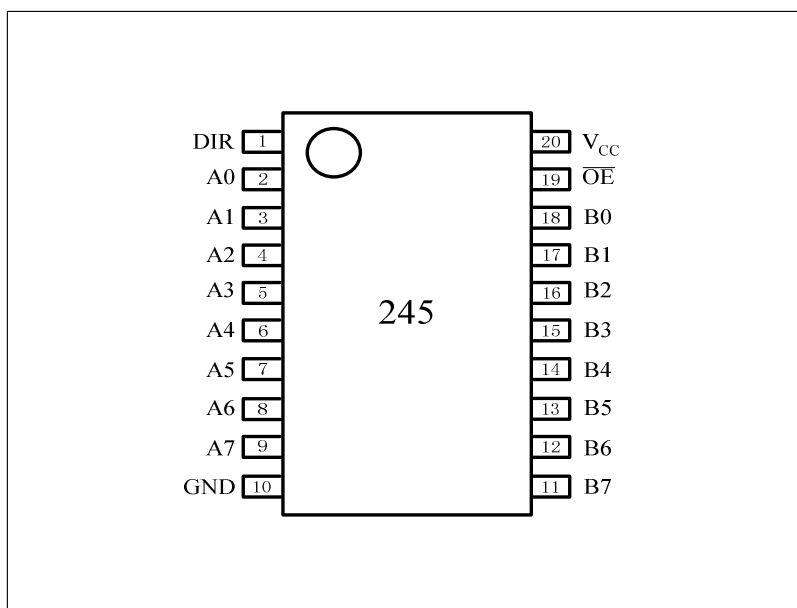
## 4. Functional Diagram



**Fig. 1** Logic symbol

## 5. Pin information

### 5.1 Pinning



**Fig. 2** Pin configuration

## 5.2 Pin Description

Table 2: Pin description

Symbol	Pin	Conditions
DIR	1	direction control
A0	2	data input/output
A1	3	data input/output
A2	4	data input/output
A3	5	data input/output
A4	6	data input/output
A5	7	data input/output
A6	8	data input/output
A7	9	data input/output
GND	10	ground (0V)
B7	11	data input/output
B6	12	data input/output
B5	13	data input/output
B4	14	data input/output
B3	15	data input/output
B2	16	data input/output
B1	17	data input/output
B0	18	data input/output
$\overline{\text{OE}}$	19	output enable input (active LOW)
VCC	20	supply voltage

## 6. Functional Description

### 6.1 Function table

Table 3: Function table \*

Input		Input/output	
$\overline{\text{OE}}$	DIR	A <sub>n</sub>	B <sub>n</sub>
0	0	A = B	input
L	H	input	B = A
H	X	Z	Z

- \* H = HIGH voltage level;  
 L = LOW voltage level;  
 X = don't care;  
 Z = high-impedance OFF-state

## 7. Limiting values

Table 4: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground =0V)

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7	V
$I_{IK}$	input diode current	$V_I < -0.5V$ or $V_I > V_{CC}+0.5V$	-	$\pm 20$	mA
$I_{OK}$	output diode current	$V_O < -0.5V$ or $V_O > V_{CC}+0.5V$	-	$\pm 20$	mA
$I_O$	output source or sink current	$V_O = -0.5V$ to $V_{CC}+0.5V$	-	$\pm 35$	mA
$I_{CC}, I_{GND}$	$V_{CC}$ or GND current		-	$\pm 70$	mA
$T_{stg}$	storage temperature		-65	+150	°C

## 8. Recommended Operating Conditions

Table 5: Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{CC}$	supply voltage		4	5	6	V
$V_I$	input voltage		0	-	$V_{CC}$	V
$V_O$	output voltage		0	-	$V_{CC}$	V
$t_r, t_f$	input rise and fall times	$V_{CC} = 4.5V$	-	6.0	500	ns
$T_{amb}$	ambient temperature		-40	-	+125	°C

## 9. Static Characteristics

Table 6: static characteristics

At recommended operating conditions; voltage are referenced to GND (ground =0V)

Symbol	Parameter	Conditions	25°C			-40°C to +85°C		-40°C to +125°C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
$V_{IH}$	HIGH-level input voltage	$V_{CC} = 2.0 V$	1.5	1.2	-	1.5	-	1.5	-	V
		$V_{CC} = 4.5 V$	3.15	2.4	-	3.15	-	3.15	-	V
		$V_{CC} = 6.0 V$	4.2	3.2	-	4.2	-	4.2	-	V
$V_{IL}$	LOW-level input voltage	$V_{CC} = 2.0 V$	-	0.8	0.5	-	0.5	-	0.5	V
		$V_{CC} = 4.5 V$	-	2.1	1.35	-	1.35	-	1.35	V
		$V_{CC} = 6.0 V$	-	2.8	1.8	-	1.8	-	1.8	V
$V_{OH}$	HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$								
		$I_O = -20 \mu A; V_{CC}=2.0V$	1.9	2.0	-	1.9	-	1.9	-	V
		$I_O = -20 \mu A; V_{CC}=4.5V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -20 \mu A; V_{CC}=6.0V$	5.9	6.0	-	5.9	-	5.9	-	V

Symbol	Parameter	Conditions	25℃			-40℃ to +85℃		-40℃ to +125℃		Unit
			Min	Typ	Max	Min	Max	Min	Max	
		$I_O = -4.0 \text{ mA}; V_{CC}=3.0\text{V}$	2.72	2.84	-	2.70	-	2.70	-	V
		$I_O = -6.5 \text{ mA}; V_{CC}=4.5\text{V}$	4.20	4.31	-	4.15	-	4.10	-	V
$V_{OL}$	LOW-level output voltage	$V_I = V_{IH} \text{ or } V_{IL}; V_{CC} = 4.5 \text{ V}$								
		$I_O = 20 \text{ uA}; V_{CC}=2.0\text{V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \text{ uA}; V_{CC}=4.5\text{V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 20 \text{ uA}; V_{CC}=6.0\text{V}$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC}=3.0\text{V}$	-	0.12	0.20	-	0.21	-	0.22	V
		$I_O = 6.5 \text{ mA}; V_{CC}=4.5\text{V}$	-	0.15	0.23	-	0.23	-	0.25	V
$I_{LI}$	Input leakage current	$V_I = V_{CC} \text{ or } GND;$ $V_{CC} = 0\text{V to } 5.5 \text{ V}$	-	-	$\pm 0.1$	-	$\pm 1.2$	-	$\pm 10$	$\mu\text{A}$
$I_{OZ}$	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL};$ $V_{CC} = 5.5 \text{ V};$ $V_O = V_{CC} \text{ or } GND;$ $I_O = 0 \text{ A}$	-	-	$\pm 0.1$	-	$\pm 0.1$	-	$\pm 1.0$	$\mu\text{A}$
$I_{CC}$	quiescent supply current	$V_I = V_{CC} \text{ or } GND; I_O = 0 \text{ A};$ $V_{CC} = 5.5 \text{ V}$	-	-	1.0	-	10.0	-	50	$\mu\text{A}$
$C_i$	input capacitance	$V_I = V_{CC} \text{ or } GND$	-	3.5	10	-	10	-	10	pF
$C_{I/O}$	input/output capacitance		-	4	-	-	-	-	-	pF

## 10. Dynamic characteristics

Table 7: Dynamic characteristics

GND = 0V; test circuit see Figure 5.

Symbol	Parameter	Conditions	25℃			-40℃ to +85℃		-40℃ to +125℃		Unit
			Min	Typ	Max	Min	Max	Min	Max	
$t_{PHL}, t_{PLH}$	propagation delay	An to Bn or Bn to An, see Figure 3								
		$V_{CC} = 2.0 \text{ V}$	-	21.0	35	-	40	-	50	ns
		$V_{CC} = 4.5 \text{ V}$	-	7.5	15	-	20	-	25	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	5.0	10	-	-	-	-	ns
		$V_{CC} = 6.0 \text{ V}$	-	6	12	-	15	-	20	ns
$t_{PZH}, t_{PZL}$	3-state output enable time	$\overline{OE}$ to An or $\overline{OE}$ to Bn, see Figure 4								
		$V_{CC} = 2.0 \text{ V}$	-	24	48		52		60	ns
		$V_{CC} = 4.5 \text{ V}$	-	10	20		24		28	ns
		$V_{CC} = 6.0 \text{ V}$	-	8	16	-	20	-	24	ns
$t_{PHZ}, t_{PLZ}$	3-state output disable time	$\overline{OE}$ to An or $\overline{OE}$ to Bn, see Figure 4								
		$V_{CC} = 2.0 \text{ V}$	-	13	26	-	30	-	40	ns
		$V_{CC} = 4.5 \text{ V}$	-	10	20	-	24	-	28	ns

		$V_{CC} = 6.0\text{ V}$	-	9	18	-	21	-	25	ns
$t_{THL}, t_{TLH}$	output transition time	see Figure 4								
		$V_{CC} = 2.0\text{ V}$	-	16	32	-	36	-	42	ns
		$V_{CC} = 4.5\text{ V}$	-	5	12	-	14	-	18	ns
		$V_{CC} = 6.0\text{ V}$	-	4	9	-	11	-	14	ns
$C_{PD}$	power dissipation capacitance per transceiver	$V_I = \text{GND}$ to $V_{CC} - 1.5\text{ V}$	-	12	-	-	-	-	-	pF

\*  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ )

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

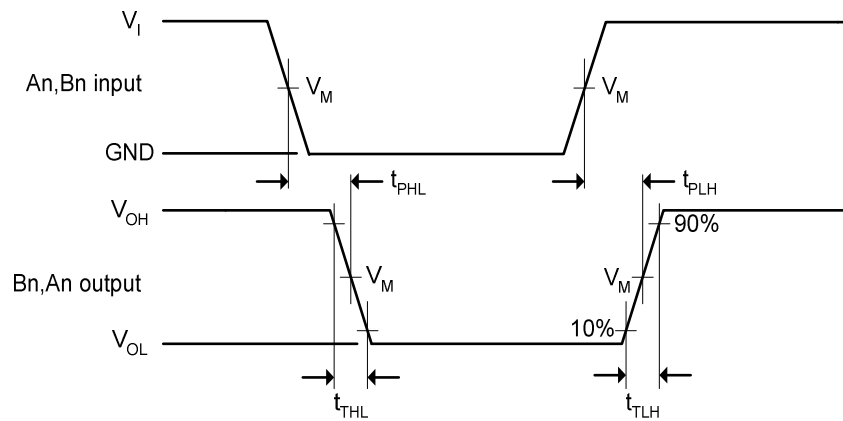
$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\sum (C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

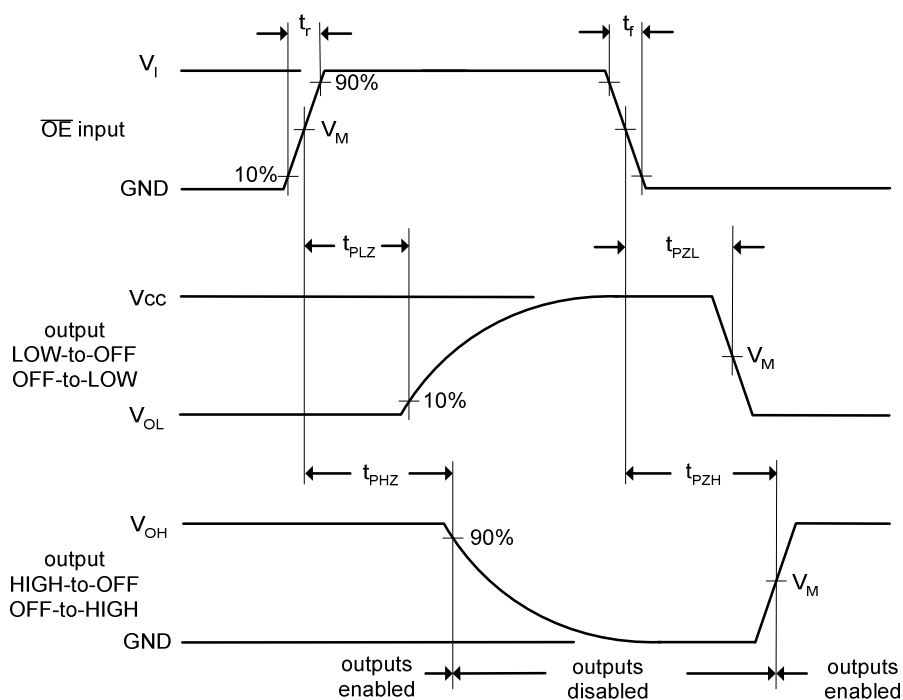
## 11. Waveforms



Measurement points are given in Table 8.

$V_{OL}$  and  $V_{OH}$  are typical voltage output drop that occur with the output load.

**Fig 3.** Input (An, Bn) to output (Bn, An) propagation delays and output transition times



Measurement points are given in Table 8.

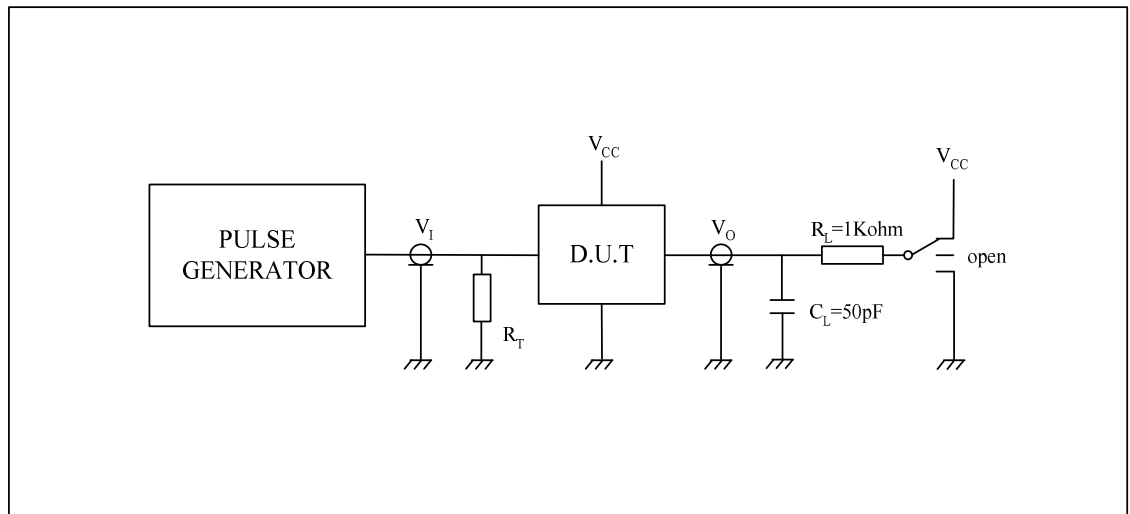
$V_{OL}$  and  $V_{OH}$  are typical voltage output drop that occur with the output load.

**Fig 4.** 3-state output enable and disable times

Table 8: Measurement points

GND =0V; test circuit see Figure 5.

Input	Output
$V_M$	$V_M$
$0.5 \cdot V_{CC}$	$0.5 \cdot V_{CC}$



Definitions test circuit:

$R_T$  = Termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.

$C_L$  = Load capacitance including jig and probe capacitance.

$R_L$  = Load resistor

**Fig. 5** Load circuitry for switching times

Table 9: Test data

Input			Output	
$V_I$	$t_r, t_f$	$t_{PHL}, t_{PLH}$	$t_{PZH}, t_{PHZ}$	$t_{PZL}, t_{PLZ}$
$V_{CC}$	6ns	open	GND	$V_{CC}$